Tuning the Phase Separation by Thermal Annealing Enables High-Performance All-Small-Molecule Organic Solar Cells

Lingxian Meng, Simin Wu, Xiangjian Wan, Zichao Shen, Mengyang Li, Yang Yang, Jian Wang, Guanghao Lu, Zaifei Ma, Zhaoyang Yao, Chenxi Li, and Yongsheng Chen*

ABSTRACT: Tuning the phase separation within the active layer morphology is of great importance for enhancing the device performance of organic solar cells (OSCs), especially for all-small-molecule OSCs (ASM-OSCs). Herein, we demonstrate that an optimal phase separation could be achieved through thermal annealing (TA) for two small-molecule acceptors, F-2Cl- and FO-2Cl-based ASM-OSCs. The acceptor FO-2Cl by introducing two oxygen atoms into the backbone of F-2Cl exhibits red-shifted absorption, enhanced crystallinity, and improved electron mobility compared with F-2Cl. When using a small-molecule C8-C-F as the donor, the ASM-OSCs of F-2Cl- and FO-2Cl showed low power conversion efficiencies (PCEs) of 5.17 and 0.64%, respectively. However, with TA treatment, the PCEs of F-2Cl- and FO-2Cl-based devices were significantly improved to 12.15 and 13.91%, respectively. It was revealed that the TA treatment could effectively tune the phase separation of the active layer morphology with the interpenetrating network and contribute to the enhanced efficiency. Additionally, with TA treatment, the blend of C8-C-F:FO-2Cl demonstrated more favorable phase separation with higher crystallinity and stronger molecular packing compared with that of C8-C-F:F-2Cl. The results demonstrate that the phase separation of ASM-OSCs can be effectively tuned by TA treatment in combination with the delicate molecular design.

1. INTRODUCTION

As an important branch of photovoltaic technology, organic solar cells (OSCs) have drawn extensive attention with the advantages of cost-effectiveness, light weight, flexibility, and translucency.1−6 With the 30-year continuous studies from the milestone work of Tang,7 OSCs have experienced a dramatic development in recent years and achieved power conversion efficiencies (PCEs) over 18%.8−14 The achievements are mainly ascribed to the design of new active layer materials, deep understanding of the device mechanism, and progress of device optimization methods,5,4,15,16 in which the active layer materials including polymers and small molecules have played a determined role to push forward the progress of the field. Compared with polymer semiconductor materials, small molecular semiconductor materials possess the merits of well-defined structures without batch-to-batch variation, easily tunable band gap, and better reproducibility.5,4,17 Thus, all-small-molecule organic solar cells (ASM-OSCs) have drawn great attention and made great progress in the past decade.17−20 However, photovoltaic performances of ASM-OSCs still largely lag behind their polymer-based counterpart, which could be mainly ascribed to the structural similarity of the donors and acceptors, especially for the widely used donor−acceptor (D−A) type donors and acceptors, which resulted in a morphology with undesirable phase separation.21−32 Therefore, it has become a major requisite to figure out effective ways to optimize the morphology to achieve high efficiency for ASM-OSCs. To this end, molecular-level optimizations, such as backbone and side chain engineering,5,13 end group modulation,34,35 etc., have been used as straightforward and effective methods to manipulate the morphology. On the other hand, many strategies of device optimizations, including solvent vapor annealing (SVA),36−38 thermal annealing (TA),31,39 additives,25,30 etc., have been successfully used to tune the film morphology and obtain excellent device performance.40,41 Among them, TA treatment can improve the crystallinity of the donor and acceptor, enhance the domain spacing and phase purity, and result in improved molecular ordering and optimal phase separation.36,42 With these, it has become a widely used strategy to...
optimize the active layer morphology and improve the device performance.

In recent years, we have developed a series of A–D–A type donor and acceptor materials. Among them, A–D–A type donor materials such as DR3TBDTT,\textsuperscript{45} DRCN5T,\textsuperscript{39} and their derivatives\textsuperscript{3,44,45} have been widely used as small molecule donors and achieved excellent performance for ASM-OSCs. Further, we have designed a series of A–D–A type acceptors based on the similar molecular design rational of A–D–A type donors. Among them, the acceptors incorporating fluorene as the central unit have been systematically investigated by our group and some representative acceptors, such as F-M,\textsuperscript{14,46,47} F-Br,\textsuperscript{46,49} F-Cl,\textsuperscript{49} and F-2Cl,\textsuperscript{23,50} have exhibited excellent photovoltaic performances in single junction, tandem, and ternary devices.\textsuperscript{14,46,47} Particularly, F-2Cl has been successfully used in ASM-OSCs with a wide band gap A–D–A type small-molecule donor DRTB-T and demonstrated an excellent performance.\textsuperscript{23} But its large band gap with an absorption onset ∼800 nm, which is far away from the preferred absorption with an onset ($\lambda_{\text{onset}}$) around 860–930 nm according to the semiempirical model analysis we have proposed,\textsuperscript{3,51} is one of the intrinsic limiting factors that impacts its photovoltaic device performance. With this, in this work, we have designed and synthesized an acceptor FO-2Cl by incorporating two oxygen atoms in the backbone of F-2Cl (Figure 1a) to move down the absorption onset. Compared with F-2Cl, FO-2Cl not only has the extended absorption range but also shows an enhanced crystallinity. Two ASM-OSCs were fabricated with F-2Cl or FO-2Cl as the acceptor and an A–D–A molecule, C8-C-F, as the donor (Figure 1a). With the as-cast blend films, two ASM-OSCs of C8-C-F:F-2Cl and C8-C-F:FO-2Cl delivered low PCEs of 5.17 and 0.64%, respectively. But after

![Figure 1](https://doi.org/10.1021/acs.chemmater.1c04293)

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Figure 1. (a) Chemical structures of F-2Cl, FO-2Cl, and C8-C-F. (b) UV–vis absorption spectra of C8-C-F, F-2Cl, and FO-2Cl in thin films. (c) Energy levels of donor and acceptors. (d) GIWAXS and in-plane and out-of-plane line-cut profiles of neat F-2Cl and FO-2Cl films. (e) Diagram of a conventional device structure. (f) J–V curves in the optimized C8-C-F:F-2Cl/FO-2Cl-based devices. (g) Statistical diagram of PCEs for 30 individual C8-C-F:FO-2Cl-based devices with TA treatment. (h) EQE spectra in the optimized C8-C-F:F-2Cl/FO-2Cl-based devices.
TA treatment, their PCEs were significantly improved to 12.15 and 13.91%, respectively. It was demonstrated that the favorable phase separation was formed in their blending films and contributed to the dramatically improved efficiencies after TA treatment. The good crystallinity and narrow band gap of FO-2Cl gave rise to its enhanced device performance compared with that of F-2Cl. The results indicate that high-performance ASM-OSCs can be realized through careful molecular design and morphology control.

2. RESULTS AND DISCUSSION

The chemical structures of F-2Cl, FO-2Cl, and C8-C-F are depicted in Figure 1a and the synthesis procedures and characterization of FO-2Cl and C8-C-F are shown in the Supporting Information. The film absorption spectra of F-2Cl and FO-2Cl, together with that of C8-C-F, are shown in Figure 1b and Table 1. Compared with F-2Cl, FO-2Cl exhibited a smaller distance of 3.46 Å in the out-of-plane (OOP), FO-2Cl displays a stronger absorption with an onset of 848 nm and an optical band gap (\(\lambda_{\text{opt}}\)) of 3.19 nm in the (010) direction. The smaller shows a larger crystal coherence length (CCL) of 3.56 nm than that of F-2Cl (3.20 nm).

Table 1. Optical and Electrochemical Data of C8-C-F, F-2Cl, and FO-2Cl

<table>
<thead>
<tr>
<th>comp.</th>
<th>(\lambda_{\text{onset}}) (nm)</th>
<th>(\lambda_{\text{max}}) (nm)</th>
<th>(J_{\text{sc}}) (mA cm(^{-2}))</th>
<th>(V_{\text{oc}}) (V)</th>
<th>FF</th>
<th>PCE (%)</th>
</tr>
</thead>
<tbody>
<tr>
<td>C8-C-F</td>
<td>518</td>
<td>575</td>
<td>702</td>
<td>1.77</td>
<td>5.17</td>
<td>0.765</td>
</tr>
<tr>
<td>F-2Cl</td>
<td>690</td>
<td>725</td>
<td>805</td>
<td>1.54</td>
<td>5.46</td>
<td>0.785</td>
</tr>
<tr>
<td>FO-2Cl</td>
<td>708</td>
<td>764</td>
<td>848</td>
<td>1.46</td>
<td>5.41</td>
<td>0.785</td>
</tr>
</tbody>
</table>

*Absorption onset of molecular films. Optical band gap was obtained from the onset wavelength of the molecular film, \(J_{\text{sc}} = 1240/\lambda_{\text{onset}}\).

Table 2. Photovoltaic Parameters of C8-C-F:F-2Cl- and C8-C-F:FO-2Cl-Based Devices under AM 1.5G Illumination (100 mW cm\(^{-2}\)) Using Conventional Device Structures

<table>
<thead>
<tr>
<th>active layers</th>
<th>temperature (°C)</th>
<th>(V_{\text{oc}}) (V)</th>
<th>FF</th>
<th>(J_{\text{sc}}) (mA/cm(^2))</th>
<th>PCE (%)</th>
</tr>
</thead>
<tbody>
<tr>
<td>C8-C-F:FO-2Cl</td>
<td>as-cast</td>
<td>0.966</td>
<td>0.491</td>
<td>10.90</td>
<td>5.17</td>
</tr>
<tr>
<td>F-2Cl</td>
<td>120</td>
<td>0.936</td>
<td>0.733</td>
<td>17.71</td>
<td>12.15</td>
</tr>
<tr>
<td>C8-C-F:FO-2Cl</td>
<td>as-cast</td>
<td>0.952</td>
<td>0.257</td>
<td>2.61</td>
<td>0.64</td>
</tr>
<tr>
<td>F-2Cl</td>
<td>140</td>
<td>0.906</td>
<td>0.765</td>
<td>20.08</td>
<td>13.91</td>
</tr>
</tbody>
</table>

*The average values in parentheses are obtained from 10 independent cells.

Table 2, with the as-cast active layer films, both the ASM-OSCs showed unfavorable performance, especially for the FO-2Cl-based device with a very low PCE of 0.64%. However, after TA treatment, the PCEs of the two ASM-OSCs were dramatically improved to 12.15 and 13.91%, respectively. Especially for the device based on FO-2Cl, its PCE was increased from 0.64% to a remarkable value of 13.91% with a high FF of 0.765 and a \(J_{\text{sc}}\) of 20.08 mA/cm\(^2\). The histograms and corresponding Gaussian distribution of PCE counting for 30 individual C8-C-F:FO-2Cl-based devices with TA treatment are shown in Figure 1g. The impressive efficiency improvement could be attributed to the formation of the favorable morphology with proper phase separation after TA treatment on the blend film, as will be discussed below. As shown in Figure 1h, with the TA treatment, compared with the F-2Cl-based device, the FO-2Cl-based device exhibited a broader EQE response, especially in the 800–850 nm region, which results in a higher \(J_{\text{sc}}\) and could be ascribed to the red-shifted absorption of the FO-2Cl-based blend film. The integrated photocurrents of C8-C-F:F-2Cl and C8-C-F:FO-2Cl from EQE curves are 17.03 and 19.37 mA cm\(^{-2}\), respectively, both of which are in good agreement with the \(J_{\text{sc}}\) values obtained from the corresponding \(J–V\) curves.

To further evaluate the influence of the molecular design with inserting oxygen atoms on the device performances, we investigated the energy loss (\(\Delta E_{\text{loss}}\)) in both ASM-OSCs. The total \(\Delta E_{\text{loss}}\) values of F-2Cl and FO-2Cl-based devices can be obtained according to the equation

\[
\Delta E_{\text{loss}} = E_{\text{fl}} - E_{\text{rad}}
\]

where \(E_{\text{fl}}\) and \(E_{\text{rad}}\) are the photoluminescence (PL) and luminescence lifetimes, respectively, which were obtained from the reduced normalized absorption and PL spectra, as shown in Figure 4. \(E_{\text{fl}}\) presents the thickness of the device, which gives the opportunity for the charge to be recombined in the device. The charge transfer from the donor to the acceptor is determined by the opportunity for charge to be recombined in the device. The charge transfer from the donor to the acceptor is determined by the opportunity for charge to be recombined in the device.
alteration of the molecular structure from F-2Cl to FO-2Cl has a positive effect in reducing the radiative recombination loss in OSCs. According to the above equation, the calculated $\Delta E_g$ ($=q\Delta V_{oc,rad} - qV_{oc}$) of the two devices are 0.254 and 0.220 eV, and the device based on FO-2Cl exhibits a smaller value than that based on F-2Cl. To further confirm $\Delta E_g$, the EQE$_{EL}$ was also measured, and according to Figure S4c, it was found that the FO-2Cl-based device exhibits a higher EQE$_{EL}$ (1.22 × 10^{-4}) than the F-2Cl-based device (6.84 × 10^{-6}), corresponding to the $\Delta V_{oc}$ of 0.300 and 0.286 V, and the trend of $\Delta V_{oc}$ is consistent with $\Delta E_g$. The detailed $E_{loss}$ values are summarized in Figure 2a and Table S7. Compared with the device of F-2Cl, the smaller $E_{loss}$ of the FO-2Cl-based device was mainly ascribed to the smaller $E_g$ and $\Delta E_g$.

To study the effect of TA treatment for the charge transport properties of the two ASM-OSCs, the space charge-limited current (SCLC) method was used to study their charge transport properties. The electron and hole mobilities can be calculated by applying the Mott–Gurney law to the $J$–$V$ characteristics of the electron-only and hole-only devices. Although the assumptions of the Mott–Gurney law are hardly always met in organic semiconductors, such as the ohmic contacts, thickness, etc., the results can be compared with each other under the same measured conditions, which have been widely used in the OSC community, as shown in Figure S5 and summarized in Table S8. For the devices with the as-cast blend films, the calculated hole and electron mobilities are 1.81 × 10^{-4} and 0.60 × 10^{-4} cm^{2}V^{-1}s^{-1} for the F-2Cl-based device and 1.41 × 10^{-4} and 2.14 × 10^{-4} cm^{2}V^{-1}s^{-1} for the FO-2Cl-based device with mobility ratios ($\mu_h/\mu_e$) of 3.02 and 0.66, respectively. The lower and unbalanced $\mu_h/\mu_e$ can be one of the reasons for the poor performance of the two ASM-OSCs, which is mainly caused by the inferior packing and unfavorable phase separation of the as-cast blend films as discussed below. After TA treatment, both the hole and electron mobilities exhibited clear enhancement with 2.04 × 10^{-4} ($\mu_h$) and 1.39 × 10^{-4} cm^{2}V^{-1}s^{-1} ($\mu_e$) for the F-2Cl-based device and 2.56 × 10^{-4} ($\mu_h$) and 3.29 × 10^{-4} cm^{2}V^{-1}s^{-1} ($\mu_e$) for the FO-2Cl-based device with $\mu_h/\mu_e$ of 1.47 and 0.78, respectively, indicating the more ordered molecular packing in the blend films after TA treatment. The FO-2Cl-based devices clearly exhibited a higher electron mobility, indicating much better ordered packing and higher crystallinity of the molecule FO-2Cl. In addition, after TA treatment, FO-2Cl-based device showed more balanced $\mu_h/\mu_e$ which supported its much higher FF.

To further understand the charge generation and dissociation behavior in the two ASM-OSCs with TA treatment, the plot of photocurrent density ($J_{ph}$) versus effective voltage ($V_{eff}$) was measured. Herein, $J_{ph} = J_L - J_D$, where $J_L$ and $J_D$ are the current density under illumination and in the dark, respectively, and $V_{eff} = V_o - V_D$ where $V_o$ is the applied voltage and $V_D$ is the voltage at $J_{ph} = 0$. As shown in Figure 2b, all of the devices reached saturation ($J_{sat}$) when the $V_{eff}$ was ~1.5 V, indicating that the charge recombination is minimized at higher voltage. The charge dissociation probability can be estimated from the ratio of $J_{ph}/J_{sat}$. Under the short-circuit conditions, the $J_{ph}/J_{sat}$ values are 91.4 and 96.6% for the F-2Cl-based and FO-2Cl-based devices, respectively, indicating the higher charge dissociation of the device based on FO-2Cl. In addition, light intensity dependence of $J_{sc}$ was also measured to further investigate recombination characteristics in the photoactive layers. As presented in Figure 2c, the recombination parameters were obtained according to the equation $J_{sc} \propto P^n$. The exponents were 0.98 for C8-C-F:F-2Cl and 0.99 for C8-C-F:FO-2Cl, potentially indicating that the bimolecular recombination was suppressed, especially for the FO-2Cl-based device. Figure 2d shows the transient photocurrent (TPC) decay kinetics of the F-2Cl- and FO-2Cl-based devices. The FO-2Cl-based device showed a relatively shorter sweepout time of 0.16 μs than that of F-2Cl-based device (0.39 μs). The relatively shorter charge extraction time at short-

![Figure 2](https://doi.org/10.1021/acs.chemmater.1c04293)

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circuit conditions is correlated to the observed weaker recombination in the FO-2Cl-based device. The above results demonstrated that in addition to the extended light absorption, the FO-2Cl-based device has higher efficiencies of charge transport and exciton dissociation compared with that of F-2Cl-based device.

Transmission electron microscopy (TEM) and atomic force microscopy (AFM) measurements were taken to investigate the active layer morphologies of the two ASM-OSCs before and after TA treatment. As displayed in the TEM images of Figure 3a–d, compared with the as-cast blend films, a more clear interpenetrating network with nanoscale phase separation can be observed for the blend films after TA treatment, especially for the film of C8-C-F:FO-2Cl. From the AFM images of Figure 3e–h, the root-mean-square (RMS) roughness of the blend films of C8-C-F:F-2Cl and C8-C-F:FO-2Cl was improved from 1.63 to 2.41 and 1.24 to 1.30 nm, respectively, and the improved RMS may be related to their enhanced packing ability, indicating that TA treatment could effectively promote the exciton dissociation and charge transportation of the all-small-molecule blends.

Grazing incidence wide-angle X-ray scattering (GIWAXS) was used to further gain insight into the molecular stacking and the influence of TA treatment. As shown in Figure S6 and Table S1, in the pristine film, the donor molecule C8-C-F shows clearly a preferential edge-on orientation with the (100) diffraction peak around 0.29 Å⁻¹ (d spacing: 22 Å) in the OOP direction and a π–π stacking (010) diffraction around 1.69 Å⁻¹ (d spacing: 3.71 Å) in the in-plane (IP) direction. In contrast, the two acceptors tend to adopt face-on orientation with intense π–π stacking (010) diffraction in the OOP direction as discussed above. As shown in Figure 3i–m, the as-cast blend films of C8-C-F:F-2Cl and C8-C-F:FO-2Cl displayed very weak stacking behaviors both in the IP and OOP directions, which might be caused by good miscibility of the small-molecule donor and acceptor. After TA treatment, although the (100) and (010) peaks in the two blend films actually become clearer and sharper in both IP and OOP directions, their morphology changes seem rather small. In fact, owing to the similarity in the chemical structure, the morphology changes in many ASM-OSCs including our case before and after TA treatment are not as clear as those in polymer/small-molecule systems whose phases of polymer and small molecules are clearly distinct. In addition, compared with the F-2Cl-based blend film, the FO-2Cl-based blend film showed larger CCL values (3.44 and 4.74 nm for FO-2Cl and 4.01 and 3.32 nm for F-2Cl in the OOP and IP directions) and smaller π–π stacking distance (3.55 and 3.58 Å for FO-2Cl and 3.60 and 3.65 Å for F-2Cl in the OOP and IP directions). The larger CCL values and smaller π–π stacking distance of the FO-2Cl-based blend film demonstrated its enhanced and more ordered packing, which is beneficial for the charge transport in the OSC device.

To further investigate the effect of TA treatment on the active layer morphologies of the two ASM-OSCs, film-depth-dependent light absorption spectra (FLAS) of the blend films without and with TA treatments on the ITO/PEDOT:PSS substrates were studied. As shown in Figure 4a,
in the C8-C:F:F:2Cl as-cast blend film, the absorption peak around 720 nm is mainly attributed to the acceptor F-2Cl, while the absorption from 500 to 680 nm is mainly derived from the donor C8-C:F. Upon TA treatment (Figure 4b), the blend film presented red-shifted absorption resulting from the stronger molecular ordering of both donor and acceptor molecules. In addition, for C8-C:F, the peak at 568 nm and the shoulder peak at 631 nm become intense and sharp, indicating an enhancement in the crystallinity of the corresponding films caused by TA treatment. In contrast, a more complicated case of the FO-2Cl-based blend film was observed as shown in Figure 4c,d. For the FO-2Cl-based as-cast blend film, the absorption of C8-C:F in the range of 500−680 nm indicated an inferior packing of the donor. Meanwhile, the maximum absorption peak of FO-2Cl was blue-shifted to 726 nm compared to its pure film with a maximum absorption peak at 764 nm, which might be caused by worse packing and phase separation of the donor and acceptor in the as-cast blend film. The worse packing of the FO-2Cl-based as-cast blend film led to the low device efficiency with a value of only 0.64%. However, after TA treatment, a new peak at 793 nm appeared due to the higher molecular ordering of FO-2Cl. Moreover, the peak of the donor also becomes intense and sharp. These results demonstrated that TA treatment could improve the molecular packing and tune the phase separation of the blend film, which is consistent with the results from TEM, AFM, GIWASX, and SCLC.

In addition, the FLAS measurement can provide the information of the film-depth-dependent electronic properties, i.e., HOMO/LUMO levels and their vertical distribution manifesting the energetic disorder of localized state dependences on the position of the film and reflecting the phase separation of the film morphology.1−6 Before reaching the electrodes, the hole/electrons hop among localized states and the energies are directly correlated with the HOMO/LUMO levels. In some systems, because of the improper vertical phase separation, HOMO/LUMO levels could have tremendous fluctuations along the film-depth direction. This could thus lead to low-energy localized states within the film and even charge traps, resulting in inferior Voc and FF. In this work, poor crystalline ordering was observed in the two blend films without TA treatment, especially for the blend film of FO-2Cl. Furthermore, their crystallinities are also dispersive along the film-depth direction, as shown by vertical fluctuation of absorption peaks (dashed lines in Figure 4a,c), corresponding to substantial dispersion of transport levels and poor photovoltaic performance. Fortunately, TA treatment changed the situation. As can be seen from the TA-treated active layers, the absorption peaks do not vary apparently along the film-depth direction, implying that the electronic transport levels have weak film-depth fluctuation and are beneficial for avoiding low-energy localized states and traps. The above results suggested that the proper phase separation with the higher molecular ordering was formed for the two ASM-OSCs after TA treatment.

3. CONCLUSIONS

In summary, we have designed and synthesized a new A−D−A type acceptor FO-2Cl by inserting two oxygen atoms in the molecular backbone of acceptor F-2Cl. Compared with F-2Cl, FO-2Cl showed red-shifted absorption and high crystallinity. With TA treatment, the PCE of C8-C:F:FO-2Cl-based ASM-OSC was improved dramatically from the value of 0.64 to 13.91%. It was found that the TA treatment could effectively manipulate the film morphology with suitable phase separation, rendering a better interpenetrating network.
Thus, the efficiencies of charge dissociation and transport could be enhanced and high photovoltaic device performance was achieved. The results highlight the importance of the new active layer material design as well as the device optimization strategy. It is believed that high efficiency ASM-OSCs can be realized through the combination of careful molecular design and morphology control.

4. EXPERIMENTAL SECTION

4.1. Materials and Synthesis. The details for the synthesis of FO-2Cl and C8-C-F are described in the Supporting Information. All of the corresponding NMR and MS spectra of the molecules are shown in Figures S7–S14.

4.2. Fabrication of OSCs. The devices were fabricated with an architecture of glass/ITO/PEDOT:PSS/active layers/PDINO/Al. The ITO-coated glass substrates were cleaned by ultrasonic treatment in the detergent, deionized water, acetone, and isopropyl alcohol under ultrasonication for 15 min each and subsequently dried using a nitrogen blower. A thin layer (~20 nm) of PEDOT:PSS (Clevios P VP AI 4083, filtered at 0.45 μm) was spin-coated at 4000 rpm onto the ITO surface. After baking at 150 °C for 20 min, the substrates were transferred into an argon-filled glovebox. Subsequently, the blend solution of C8-C-F:2Cl or C8-C-F:FO-2Cl (1:0.8 w/w, 8 mg/mL from CF) was spin-coated to form the active layers with a thickness of 120 nm. Then, the substrates were thermally treated at 120 °C for C8-C-F:2Cl and 140 °C for C8-C-F:FO-2Cl. After that, the methanol solution of PDINO (1 mg/mL) was spin-coated on the top of active layers at 3000 rpm. Finally, 50 nm Al layers were deposited under high vacuum (~1.5 × 10⁻⁷ Pa). The effective areas of cells were 4 mm², defined by shallow masks.

4.3. Characterization of Films and Devices. The current density–voltage (J–V) curves of photovoltaic devices were obtained by a Keithley 2400 source-measure unit. The photocurrent was measured under AM 1.5G illumination at 100 mW cm⁻². The external quantum efficiency (EQE) spectrum was measured using a QE−R Solar Cell Spectral Response Measurement System (Enli Technology Co., Ltd., Taiwan).

ASSOCIATED CONTENT

Supporting Information

The Supporting Information is available free of charge at https://pubs.acs.org/doi/10.1021/acs.chemmater.1c04293.

Synthetic route of the molecules, DFT calculations, CV, UV–vis, SCLC, GIWAXS patterns, and additional tables (PDF)

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Notes

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